



# STC08DE150HV

Hybrid emitter switched bipolar transistor  
ESBT® 1500 V - 8 A - 0.075  $\Omega$

## Features

$V_{CS(ON)}$	$I_C$	$R_{CS(ON)}$
0.6 V	8 A	0.075 $\Omega$

- Low equivalent ON resistance
- Very fast-switch: up to 150 kHz
- Squared RBSOA: up to 1500 V
- Very low  $C_{ISS}$  driven by  $R_G = 47 \Omega$

## Application

- Single switch SMPS based on three-phase mains

## Description

The STC08DE150HV is manufactured in a hybrid structure, using dedicated high voltage bipolar and low voltage MOSFET technologies, aimed at providing the best performance in an ESBT topology.

The STC08DE150HV is designed for use in auxiliary flyback SMPS for any three-phase application.

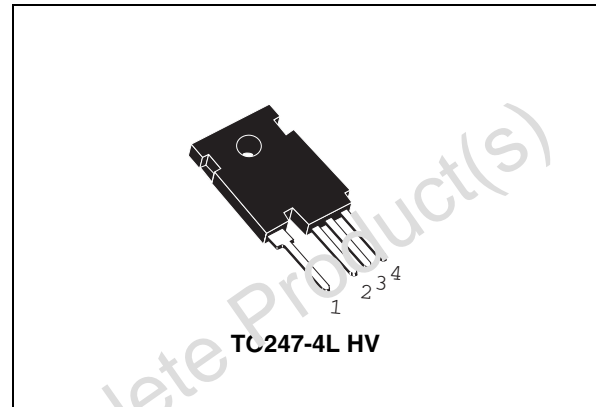


Figure 1. Internal schematic diagrams

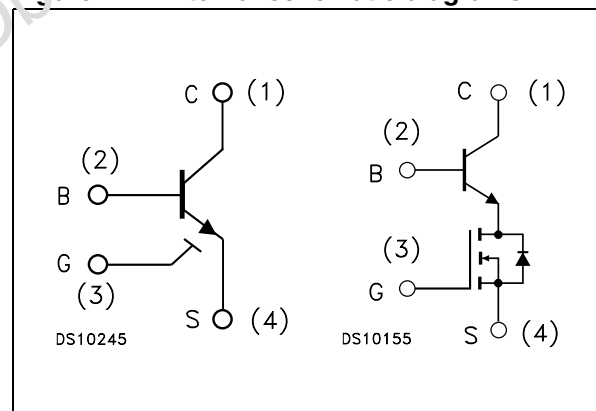


Table 1. Device summary

Order code	Marking	Package	Packing
STC08DE150HV	C08DE150HV	TO247-4L HV	Tube

# 1 Electrical ratings

**Table 2. Absolute maximum ratings**

Symbol	Parameter	Value	Unit
$V_{CS(SS)}$	Collector-source voltage ( $V_{BS} = V_{GS} = 0$ )	1500	V
$V_{BS(OS)}$	Base-source voltage ( $I_C = 0$ , $V_{GS} = 0$ )	30	V
$V_{SB(OS)}$	Source-base voltage ( $I_C = 0$ , $V_{GS} = 0$ )	9	V
$V_{GS}$	Gate-source voltage	$\pm 20$	V
$I_C$	Collector current	8	A
$I_{CM}$	Collector peak current ( $t_P < 5$ ms)	15	A
$I_B$	Base current	8	A
$I_{BM}$	Base peak current ( $t_P < 1$ ms)	15	A
$P_{tot}$	Total dissipation at $T_c \leq 25$ °C	156	W
$T_{stg}$	Storage temperature	-40 to 150	°C
$T_J$	Max. operating junction temperature	125	°C

**Table 3. Thermal data**

Symbol	Parameter	Value	Unit
$R_{thJC}$	Thermal resistance junction-case	0.64	°C/W

## 2 Electrical characteristics

( $T_{\text{case}} = 25^{\circ}\text{C}$  unless otherwise specified)

**Table 4. Electrical characteristics**

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
$I_{\text{CS(SS)}}$	Collector cut-off current ( $V_{\text{BS}} = V_{\text{GS}} = 0$ )	$V_{\text{CS}} = 1500 \text{ V}$			100	$\mu\text{A}$
$I_{\text{BS(OS)}}$	Base cut-off current ( $I_{\text{C}} = 0, V_{\text{GS}} = 0$ )	$V_{\text{BS}} = 30 \text{ V}$			10	$\mu\text{A}$
$I_{\text{SB(OS)}}$	Source cut-off current ( $I_{\text{C}} = 0, V_{\text{GS}} = 0$ )	$V_{\text{SB}} = 9 \text{ V}$			100	$\mu\text{A}$
$I_{\text{GS(OS)}}$	Gate-source leakage current ( $V_{\text{BS}} = 0$ )	$V_{\text{GS}} = \pm 20 \text{ V}$			500	nA
$V_{\text{CS(ON)}}$	Collector-source ON voltage	$V_{\text{GS}} = 10 \text{ V} \quad I_{\text{C}} = 8 \text{ A} \quad I_{\text{B}} = 1.6 \text{ A}$ $V_{\text{GS}} = 10 \text{ V} \quad I_{\text{C}} = 5 \text{ A} \quad I_{\text{B}} = 0.5 \text{ A}$		0.6 0.6	1.4 V	V V
$h_{\text{FE}}^{(1)}$	DC current gain	$I_{\text{C}} = 8 \text{ A} \quad V_{\text{CS}} = 1 \text{ V} \quad V_{\text{GS}} = 10 \text{ V}$ $I_{\text{C}} = 5 \text{ A} \quad V_{\text{CS}} = 1 \text{ V} \quad V_{\text{GS}} = 10 \text{ V}$	4.5 8	7.5 10		
$V_{\text{BS(ON)}}$	Base-source ON voltage	$V_{\text{GS}} = 10 \text{ V} \quad I_{\text{C}} = 8 \text{ A} \quad I_{\text{B}} = 1.6 \text{ A}$ $V_{\text{GS}} = 10 \text{ V} \quad I_{\text{C}} = 5 \text{ A} \quad I_{\text{B}} = 0.5 \text{ A}$		1.5 1	2 V	V V
$V_{\text{GS(th)}}$	Gate threshold voltage	$V_{\text{BS}} = V_{\text{GS}} \quad I_{\text{B}} = 250 \mu\text{A}$	1.5	2.2	3	V
$C_{\text{iss}}$	Input capacitance ( $V_{\text{GS}} = V_{\text{CB}} = 0$ )	$V_{\text{CS}} = 25 \text{ V} \quad f = 1 \text{ MHz}$		750		pF
$Q_{\text{GS(tot)}}$	Gate-source charge ( $V_{\text{CS}} = 0$ )	$V_{\text{GS}} = 10 \text{ V} \quad I_{\text{C}} = 8 \text{ A} \quad V_{\text{CS}} = 25 \text{ V}$		12.5		nC
$t_{\text{r}}$ $t_{\text{f}}$	Inductive load Storage time Fall time	$V_{\text{GS}} = 10 \text{ V} \quad R_{\text{G}} = 47 \Omega$ $V_{\text{Clamp}} = 1200 \text{ V} \quad t_{\text{p}} = 4 \mu\text{s}$ $I_{\text{C}} = 5 \text{ A} \quad I_{\text{B}} = 0.5 \text{ A}$		526 8.5		ns ns
$t_{\text{r}}$ $t_{\text{f}}$	Inductive load Storage time Fall time	$V_{\text{GS}} = 10 \text{ V} \quad R_{\text{G}} = 47 \Omega$ $V_{\text{Clamp}} = 1200 \text{ V} \quad t_{\text{p}} = 4 \mu\text{s}$ $I_{\text{C}} = 5 \text{ A} \quad I_{\text{B}} = 1 \text{ A}$		884 16		ns ns
$V_{\text{CSW}}$	Maximum collector-source voltage at turn-off without snubber	$R_{\text{G}} = 47 \Omega \quad h_{\text{FE}} = 5 \quad I_{\text{C}} = 8 \text{ A}$	1500			V
$V_{\text{CS(dyn)}}$	Collector-source dynamic voltage (0.5 $\mu\text{s}$ )	$V_{\text{CC}} = V_{\text{Clamp}} = 300 \text{ V}$ $V_{\text{GS}} = 10 \text{ V} \quad I_{\text{C}} = 4 \text{ A}$ $I_{\text{B}} = 0.8 \text{ A} \quad t_{\text{peak}} = 500 \text{ ns}$ $R_{\text{G}} = 47 \Omega \quad I_{\text{Bpeak}} = 8 \text{ A} (2I_{\text{C}})$		6		V
$V_{\text{CS(dyn)}}$	Collector-source dynamic voltage (1 $\mu\text{s}$ )	$V_{\text{CC}} = V_{\text{Clamp}} = 300 \text{ V}$ $V_{\text{GS}} = 10 \text{ V} \quad I_{\text{C}} = 4 \text{ A}$ $I_{\text{B}} = 0.8 \text{ A} \quad t_{\text{peak}} = 500 \text{ ns}$ $R_{\text{G}} = 47 \Omega \quad I_{\text{Bpeak}} = 8 \text{ A} (2I_{\text{C}})$		2.2		V

1. Pulsed duration = 300  $\mu\text{s}$ , duty cycle  $\leq 1.5\%$

2.1 Electrical characteristics (curves)

Figure 2. Output characteristics

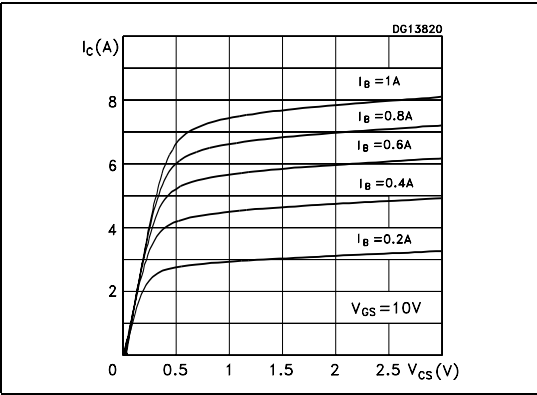


Figure 3. Collector-source dynamic voltage

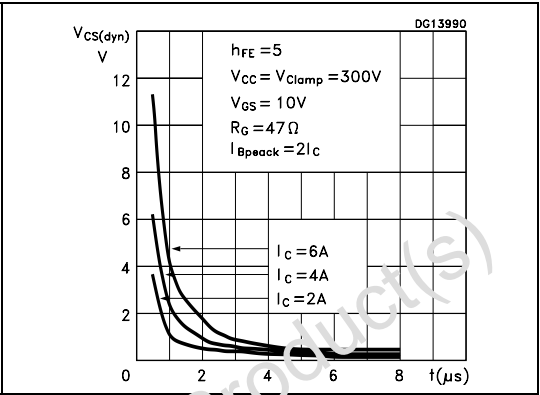


Figure 4. DC current gain

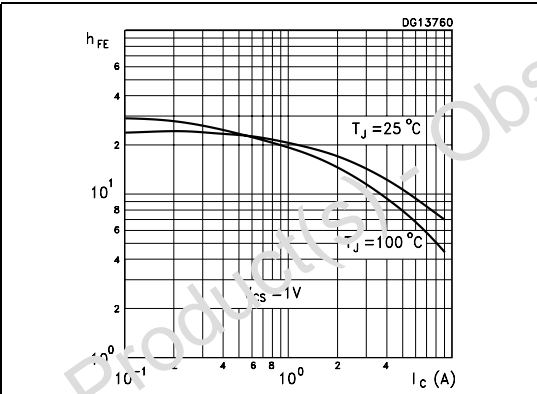


Figure 5. Gate threshold voltage vs. temperature

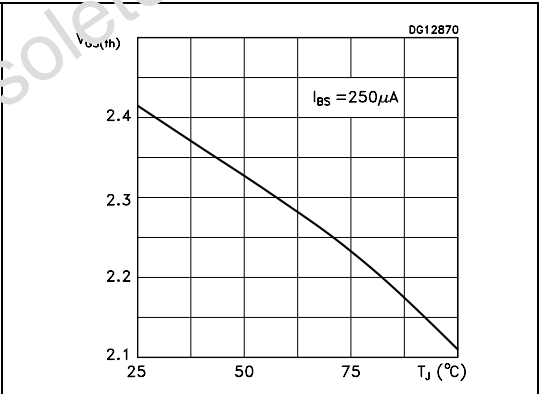


Figure 6. Collector-source ON voltage ( $h_{FE} = 5$ )

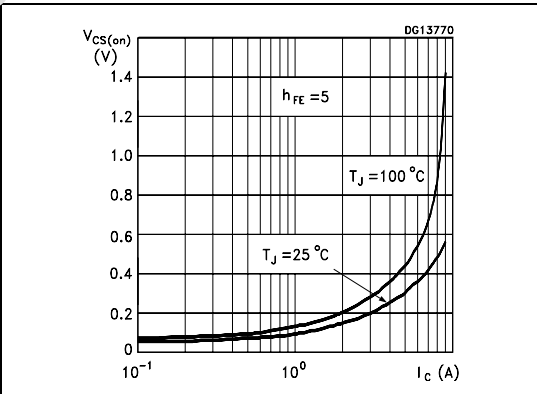


Figure 7. Collector-source ON voltage ( $h_{FE} = 10$ )

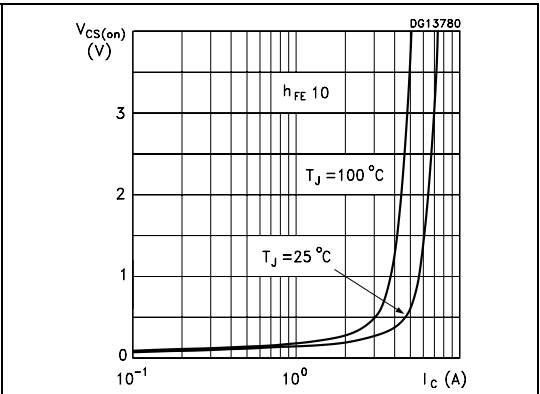


Figure 8. Base-source ON voltage  
( $h_{FE} = 5$ )

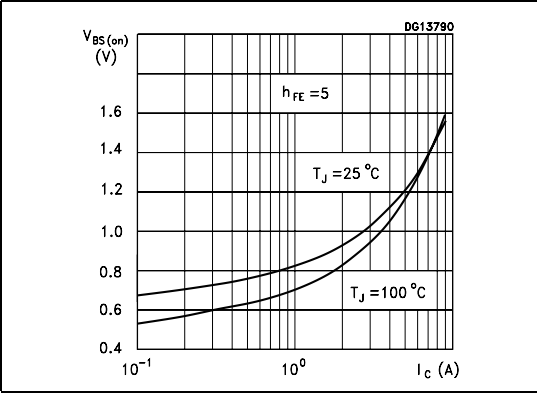


Figure 9. Base-source ON voltage  
( $h_{FE} = 10$ )

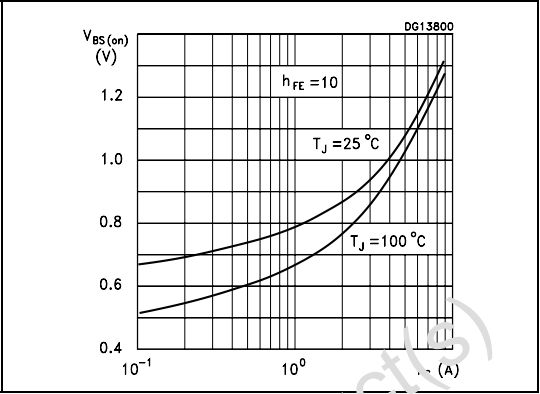


Figure 10. Inductive load switching time  
( $h_{FE} = 5$ )

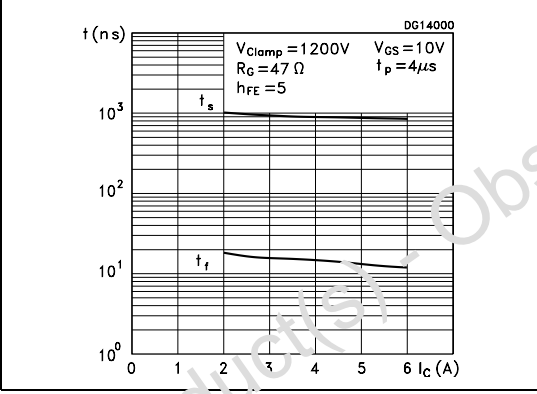


Figure 11. Inductive load switching time  
( $h_{FE} = 10$ )

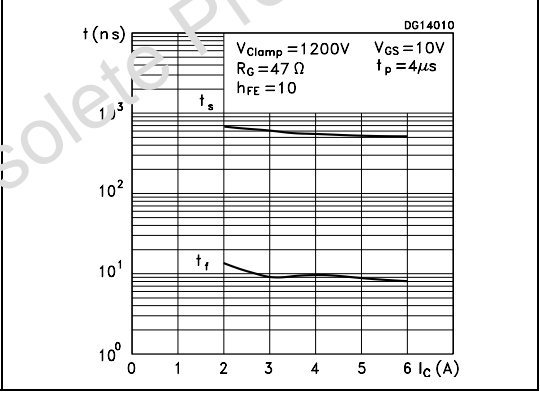
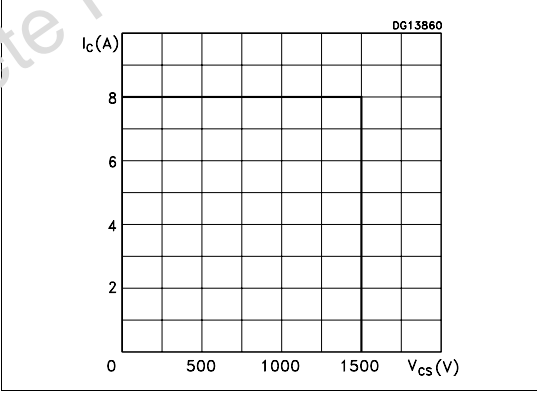


Figure 12. Reverse biased safe  
operating area



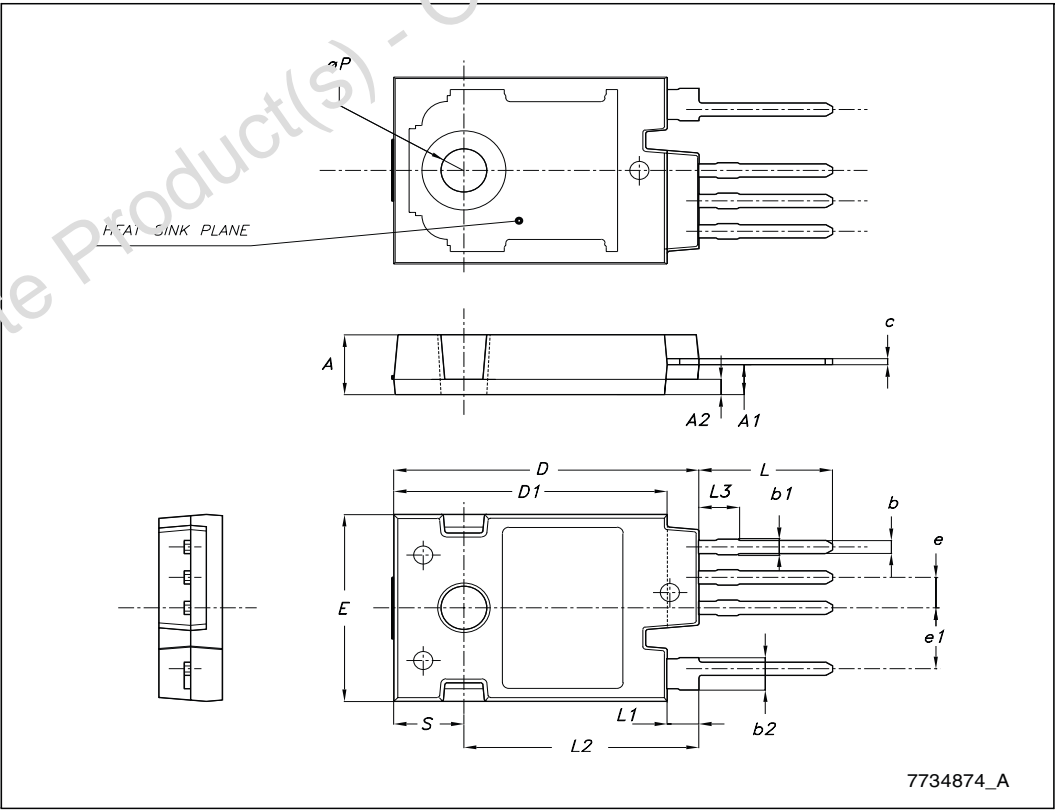
### 3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: [www.st.com](http://www.st.com). ECOPACK® is an ST trademark.

Obsolete Product(s) - Obsolete Product(s)

TO247-4L HV mechanical data

DIM.	mm.		
	MIN.	TYP	MAX.
A	4.85		5.15
A1	2.20	2.50	2.60
A2		1.27	
b	0.95	1.10	1.30
b1	1.10		1.50
b2	2.50		2.90
c	0.40		0.80
D	23.85	24	24.15
D1		21.50	
E	15.45	15.60	15.75
e		2.54	
e1		5.08	
L	10.20		10.80
L1	2.20	2.50	2.80
L2		18.50	
L3		5	
øP	3.55		3.65
S		5.50	



## 4 Revision history

**Table 5. Document revision history**

Date	Revision	Changes
25-Oct-2006	1	First release.
17-Jun-2009	2	Document status promoted from preliminary data to datasheet.



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